



Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from,Europe,America and south Asia,supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of “Quality Parts,Customers Priority,Honest Operation,and Considerate Service”,our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip,ALPS,ROHM,Xilinx,Pulse,ON,Everlight and Freescale. Main products comprise IC,Modules,Potentiometer,IC Socket,Relay,Connector.Our parts cover such applications as commercial,industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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ULTRAFAST RECTIFIERS, High Efficiency 25A and 30A

High-Reliability
screening available

DESCRIPTION

The UES701(HR2) through UES703(HR2) series of ultrafast high-efficiency rectifiers is specifically designed for operation in power switching circuits operating at frequencies of 20 kHz or higher. The low thermal resistance and forward voltage drop of this series allows the user to replace larger DO-5 packaged devices in many applications. Microsemi also offers numerous other products to meet higher and lower power voltage regulation applications.

Important: For the latest information, visit our website <http://www.microsemi.com>.

FEATURES

- Very low forward voltage (0.825 V @ $I_F = 25$ A).
- Very fast recovery times (35-50 ns).
- Low thermal resistance.
- High reliability screening option.
- Mechanically rugged.
- Both polarities available.
- RoHS compliant devices available by adding "e3" suffix (commercial grade only).

APPLICATIONS / BENEFITS

- Power switching circuits 20 kHz and above with minimal parasitic switching losses.
- Catch diodes for switching regulators.
- Output rectifiers for high frequency square-wave inverters.
- Extremely robust in power cycling.
- High surge capability.
- Hermetically sealed.

MAXIMUM RATINGS

| Parameters/Test Conditions | Symbol | Value | Unit |
|--|---------------------|-------------|------|
| Junction and Storage Temperature | T_J and T_{STG} | -55 to +175 | °C |
| Thermal Resistance Junction-to-Case | $R_{\theta JC}$ | 1.5 | °C/W |
| Working Peak Reverse Voltage | V_{RWM} | UES701 | 50 |
| | | UES702 | 100 |
| | | UES703 | 150 |
| Repetitive Peak Reverse Voltage | V_{RRM} | UES701 | 50 |
| | | UES702 | 100 |
| | | UES703 | 150 |
| RMS Forward Current | $I_{F(RMS)}$ | 40 | Amps |
| Non-Repetitive Sinusoidal Surge Current (8.3 ms) | I_{FSM} | 400 | Amps |
| Maximum Average DC Output Current @ T_C 100 °C | I_O | 25 | Amps |



DO-4 Package

MSC – Lawrence

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(978) 620-2600
Fax: (978) 689-0803

MSC – Ireland

Gort Road Business Park,
Ennis, Co. Clare, Ireland
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Website:

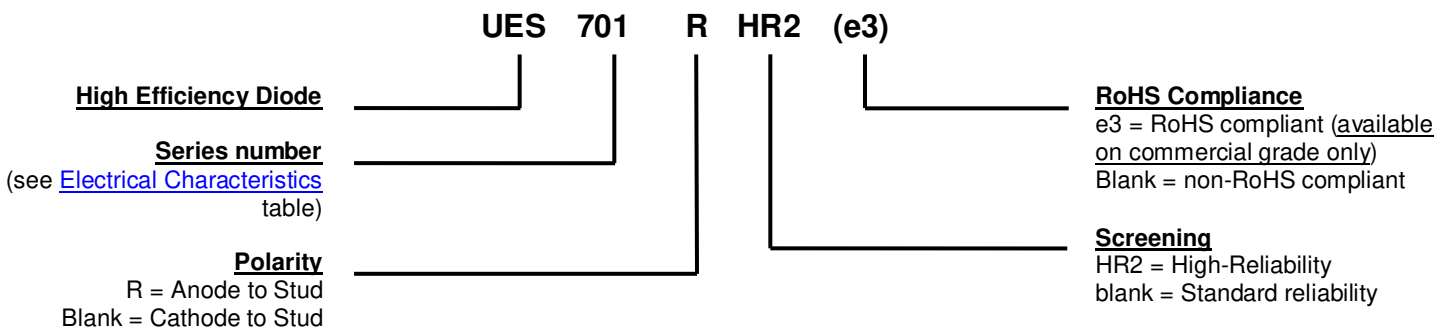
www.microsemi.com

MECHANICAL and PACKAGING

- CASE: Hermetically sealed metal and glass case body with 7/16 inch hex and 10-32 threaded stud.
- TERMINALS: Tin-lead plated or RoHS compliant matte-tin plating (commercial grade only) on nickel.
- MARKING: Part number.
- WEIGHT: 10 grams (approximate).
- Maximum Stud Torque: 10 inch pounds.
- See [Package Dimensions](#) on last page.

OPTIONAL HIGH RELIABILITY (HR2) SCREENING

| SCREEN | MIL-STD-750 METHOD | CONDITIONS |
|---|--------------------|--|
| 1. High Temperature | 1032 | 24 Hours @ $T_A = 150^{\circ}\text{C}$ |
| 2. Temperature Cycle | 1051 | F, 20 Cycles, -55 to $+150^{\circ}\text{C}$. No dwell required @ 25°C , $T \geq 10$ min. @ extremes |
| 3. Hermetic Seal a. Fine Leak b. Gross Leak | 1071 | H, Helium C, Liquid |
| 4. Thermal Impedance | 3101 | |
| 5. Interim Electrical Parameters | GO/NO GO | As applicable |
| 6. High Temperature Reverse Bias (HTRB) | As Applicable | $t = 48$ hours, $T_c = 125^{\circ}\text{C}$ with applicable bias conditions |
| 7. Final Electrical Parameters | GO/NO GO | As applicable |

PART NOMENCLATURE


SYMBOLS & DEFINITIONS

| Symbol | Definition |
|-----------|---|
| I_F | Forward Current: The forward current dc value, no alternating component. |
| I_{FSM} | Maximum Forward Surge Current: The forward current, surge peak or rated forward surge current. |
| I_O | Average Rectified Output Current: The Output Current averaged over a full cycle with a 50 Hz or 60 Hz sine-wave input and a 180 degree conduction angle. |
| I_R | Reverse Current: The maximum reverse (leakage) current that will flow at the specified voltage and temperature. |
| t_{rr} | Reverse Recovery Time: The time interval between the instant the current passes through zero when changing from the forward direction to the reverse direction and a specified decay point after a peak reverse current occurs. |
| V_F | Maximum Forward Voltage: The maximum forward voltage the device will exhibit at a specified current. |
| V_R | Reverse Voltage: The reverse voltage dc value, no alternating component. |
| V_{RRM} | Repetitive Peak Reverse Voltage: The peak reverse voltage including all repetitive transient voltages but excluding all non-repetitive transient voltages. |
| V_{RWM} | Working Peak Reverse Voltage: The maximum peak voltage that can be applied over the operating temperature range excluding all transient voltages (ref JESD282-B). Also sometimes known as PIV. |

ELECTRICAL CHARACTERISTICS

| Type | Maximum Forward Voltage V_F | | | Maximum Reverse Current I_R | | | Maximum Reverse Recovery Time t_{rr} |
|----------------------------|------------------------------------|---------------------------|-------------------------------------|------------------------------------|---------------------------|---------------------------|---|
| | $T_c = 25^\circ\text{C}$ | $T_c = 100^\circ\text{C}$ | $T_c = 125^\circ\text{C}$ | $T_c = 25^\circ\text{C}$ | $T_c = 100^\circ\text{C}$ | $T_c = 125^\circ\text{C}$ | |
| UES701 UES702 UES703 | 0.95 V @ $I_F = 25\text{ A}$ | N/A | 0.825 V @ $I_F = 25\text{ A}$ | 20 μA @ V_{RWM} | N/A | 4 mA @ V_{RWM} | 35 ns ⁽¹⁾ |

NOTES: 1. Measured in circuit $I_F = 0.5\text{ A}$, $I_R = 1\text{ A}$, $I_{REC} = 0.25\text{ A}$.

GRAPHS

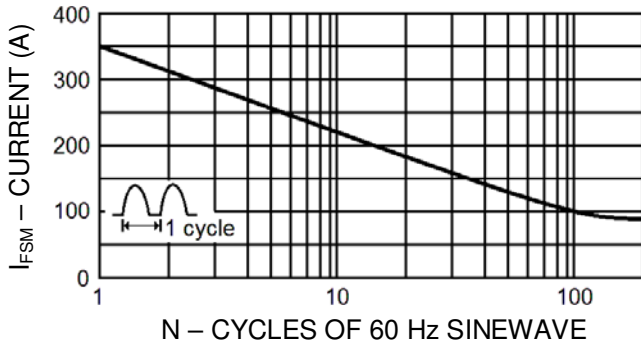


FIGURE 1

Maximum Forward Surge vs Number of Cycles

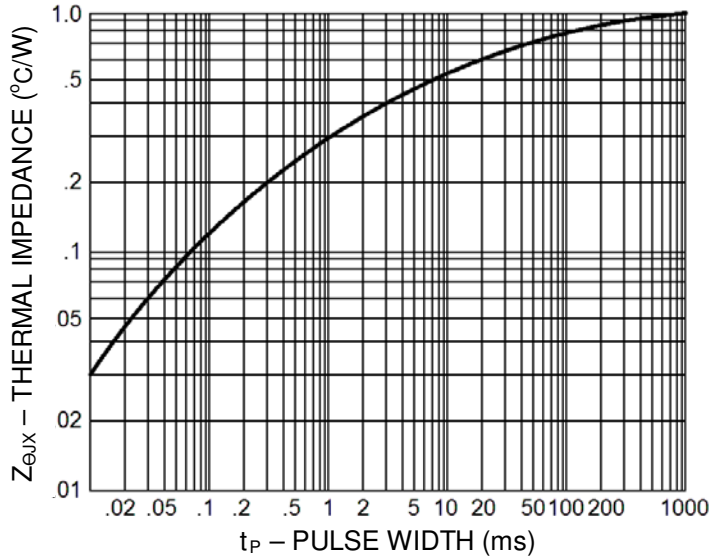


FIGURE 2

Thermal Impedance vs. Pulse Width

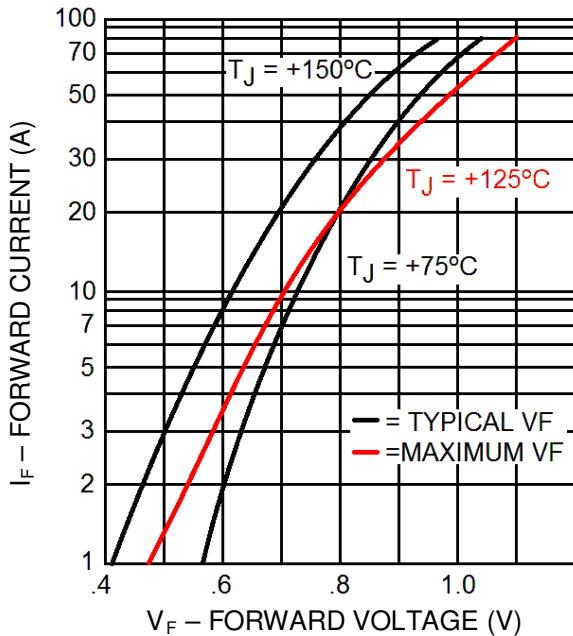


FIGURE 3

Forward Current vs. Forward Voltage

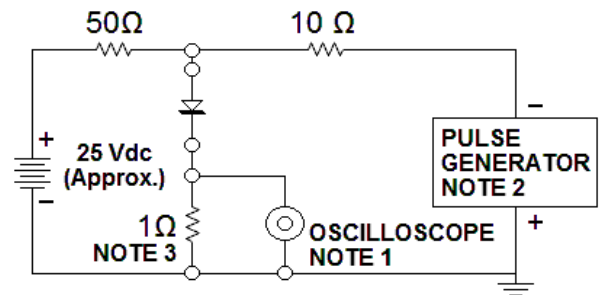


FIGURE 4

Reverse-Recovery Circuit

NOTES:

1. Oscilloscope: Rise time ≤ 3 ns; input impedance = 50Ω .
2. Pulse Generator: Rise time ≤ 8 ns; source impedance 10Ω .
3. Current viewing resistor, non-inductive, coaxial recommend.

GRAPHS (continued)

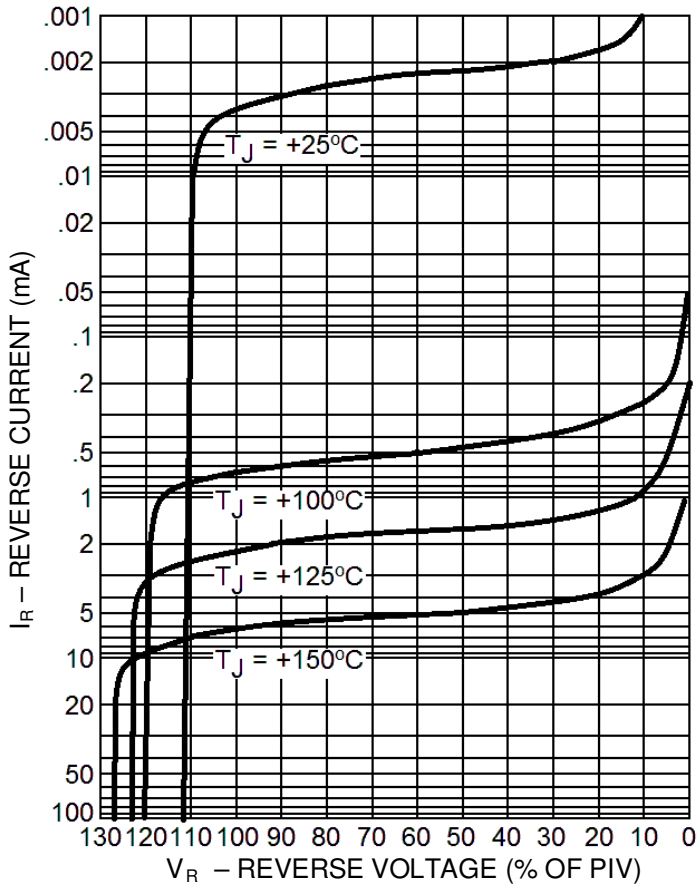


FIGURE 5
Typical Reverse Current vs. Reverse Voltage

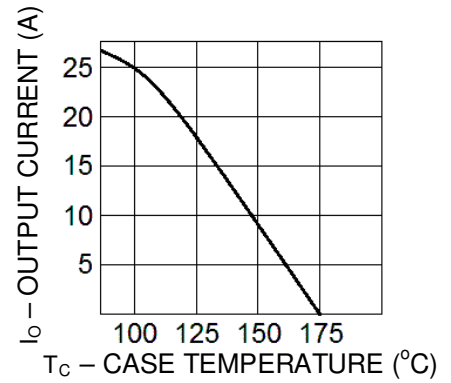
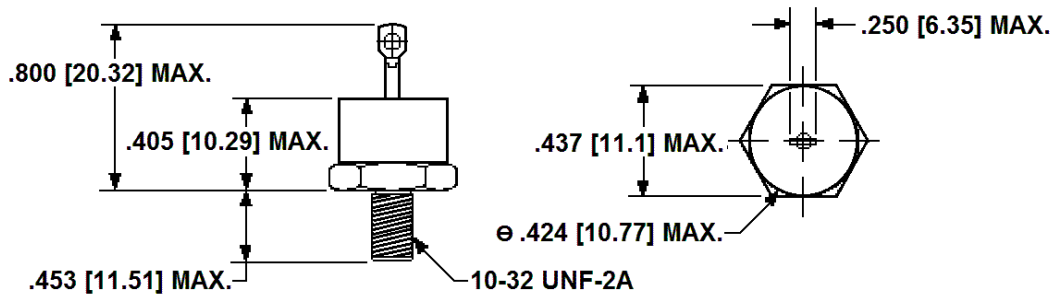


FIGURE 6
Output Current vs. Case Temperature

PACKAGE DIMENSIONS**NOTES:**

1. Dimensions in inch [mm].
2. All metal surfaces tin-lead plated.
3. Maximum stud torque: 10 inch pounds.